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2SA1785/2SC4645

2SA1785 : PNP Epitaxial Planar Silicon Transistor
2SC4645 : NPN Triple Diffused Planar Silicon Transistor
High Voltage Driver Applications

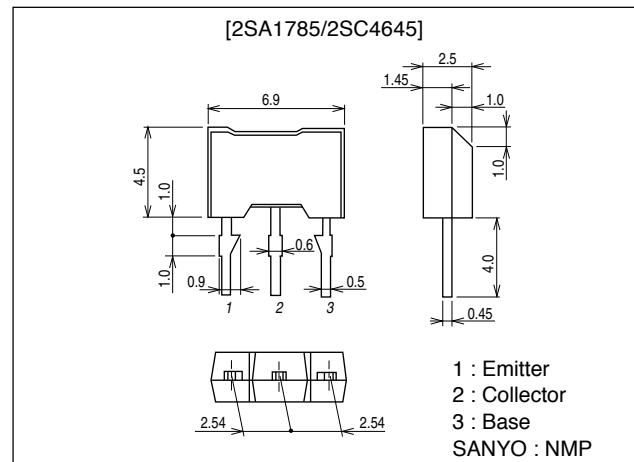
Features

- Large current capacity ($I_C=1A$).
- High breakdown voltage ($V_{CEO} \geq 400V$).

Package Dimensions

unit:mm

2064A



() : 2SA1785

Specifications

Absolute Maximum Ratings at $T_a = 25^\circ C$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		(-400)	V
Collector-to-Emitter Voltage	V_{CEO}		(-400)	V
Emitter-to-Base Voltage	V_{EBO}		(-5)	V
Collector Current	I_C		(-1)	A
Collector Current (Pulse)	I_{CP}		(-2)	A
Collector Dissipation	P_C		1	W
Junction Temperature	T_J		150	$^\circ C$
Storage Temperature	T_{stg}		-55 to +150	$^\circ C$

Electrical Characteristics at $T_a = 25^\circ C$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=(-)300V, I_E=0$			(-1.0)	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=(-)4V, I_C=0$			(-1.0)	μA
DC Current Gain	h_{FE}	$V_{CE}=(-)10V, I_C=(-)100mA$	40*		200*	
Gain-Bandwidth Product	f_T	$V_{CE}=(-)10V, I_C=(-)50mA$		(50)70		MHz
Output Capacitance	C_{ob}	$V_{CB}=(-)30V, f=1MHz$		(12)8		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)200mA, I_B=(-)20mA$			(-1.0)	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)200mA, I_B=(-)20mA$			(-1.0)	V

* : The 2SA1785/2SC4645 are classified by 100mA h_{FE} as follows :

Rank	C	D	E
h_{FE}	40 to 80	60 to 120	100 to 200

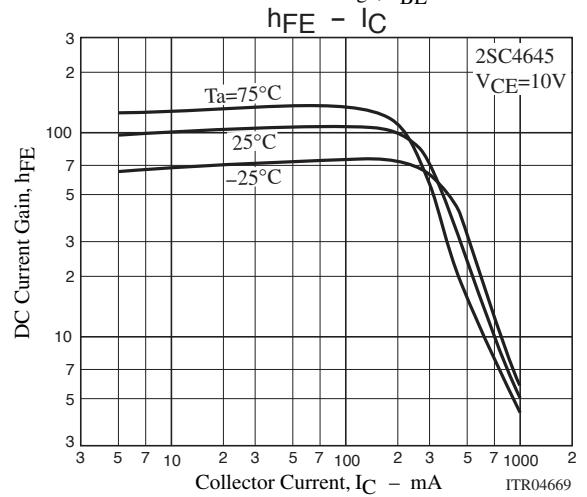
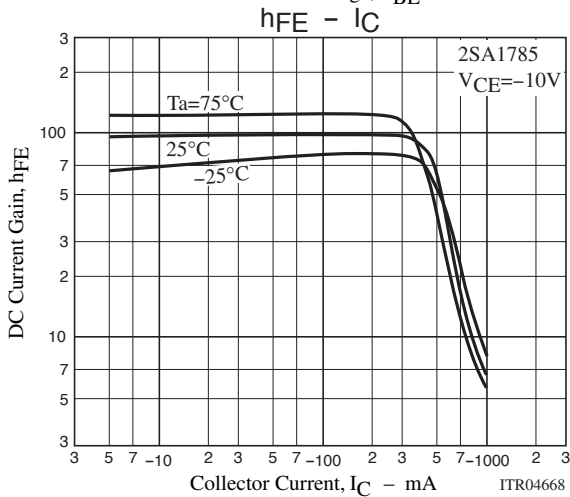
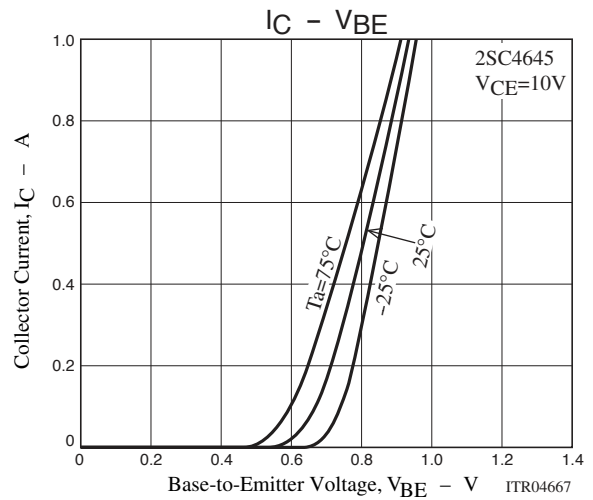
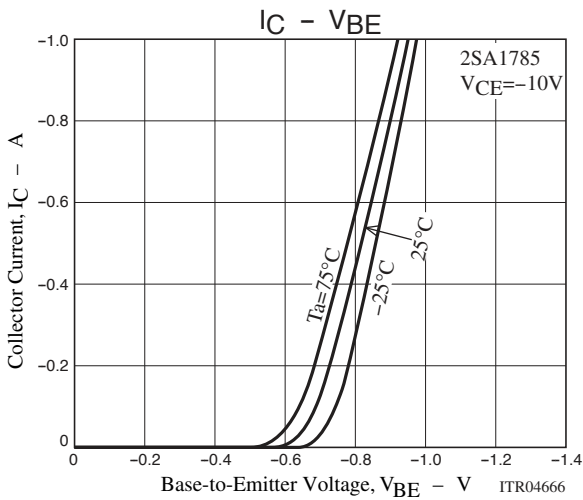
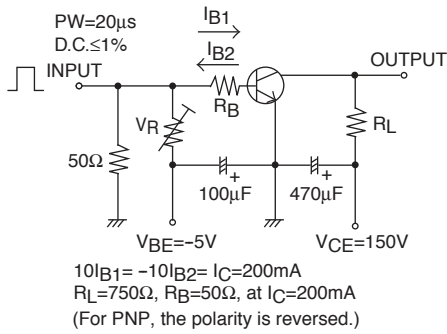
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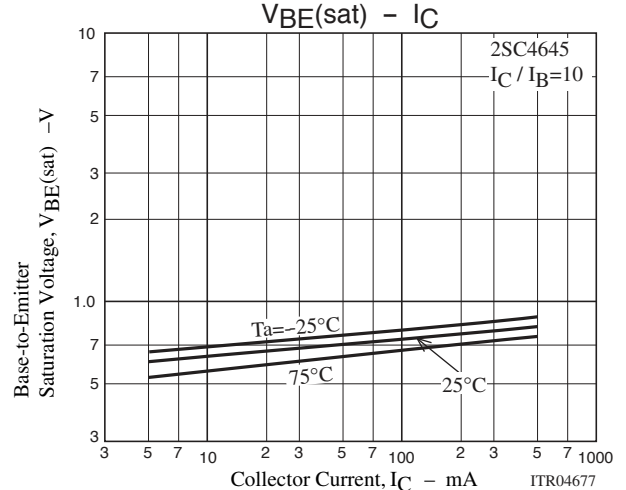
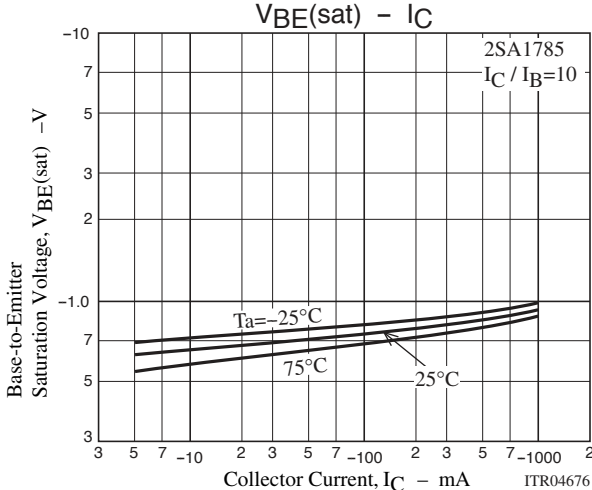
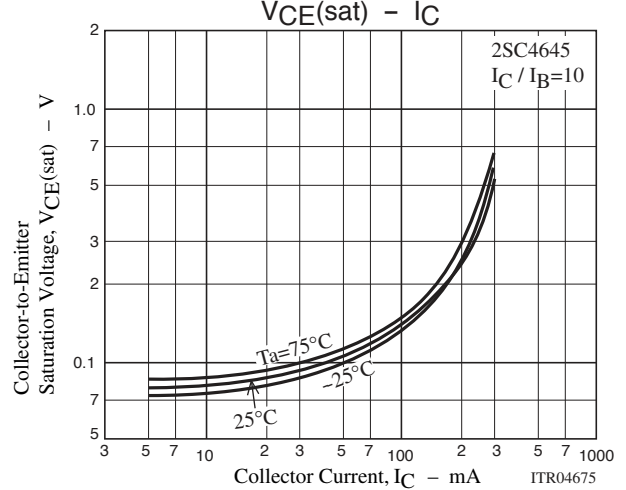
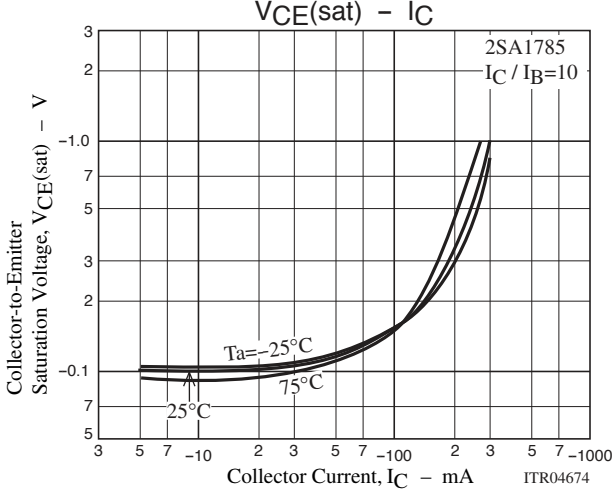
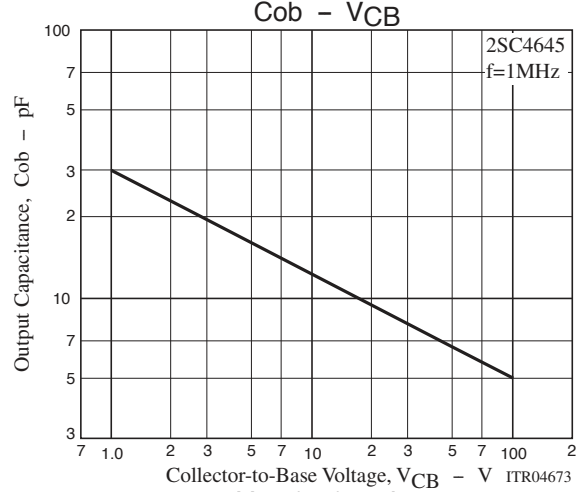
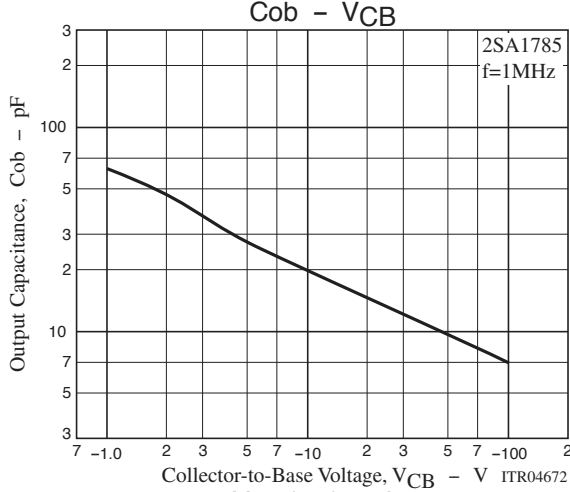
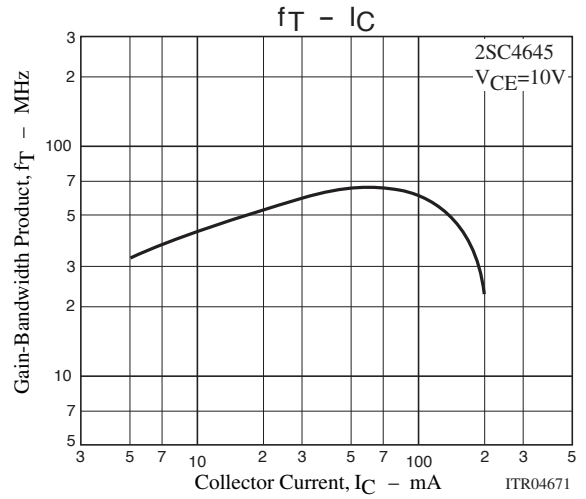
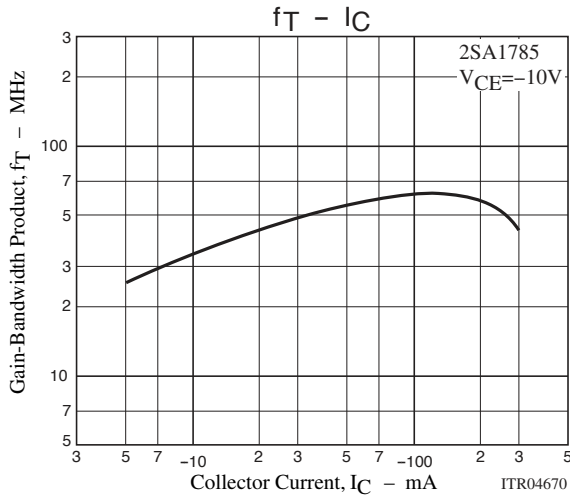
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = (-)10\mu A, I_E = 0$	(-)400			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = (-)1mA, R_{BE} = \infty$	(-)400			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = (-)10\mu A, I_C = 0$	(-)5			V
Turn-ON Time	t_{on}	See specified Test Circuit		(0.25)		μs
				0.11		μs
Storage Time	t_{stg}	See specified Test Circuit		(3.0)		μs
				4.0		μs
Fall Time	t_f	See specified Test Circuit		(0.3)		μs
				0.65		μs

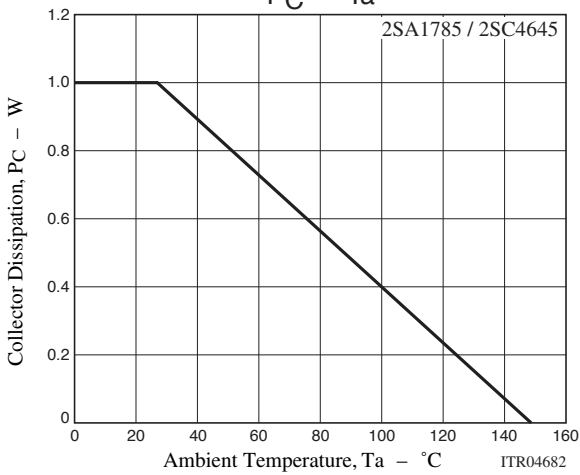
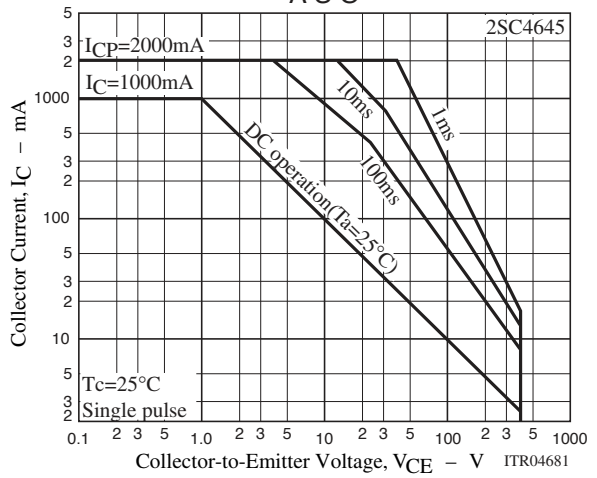
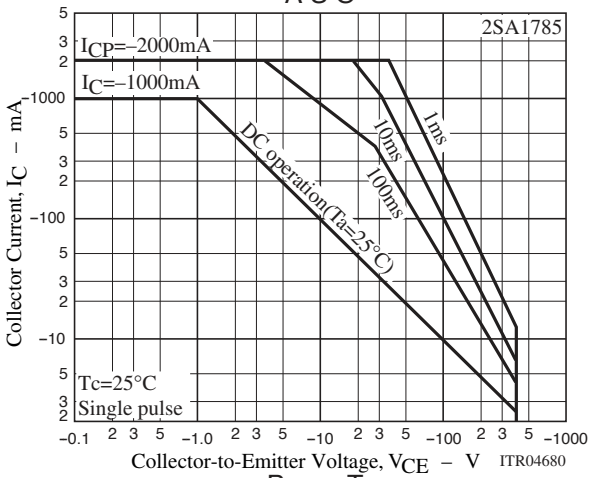
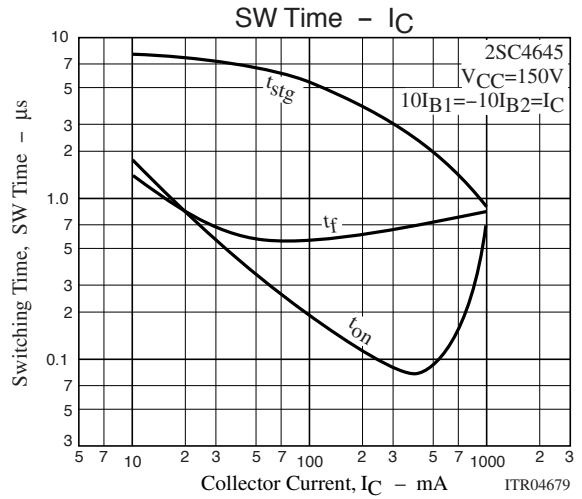
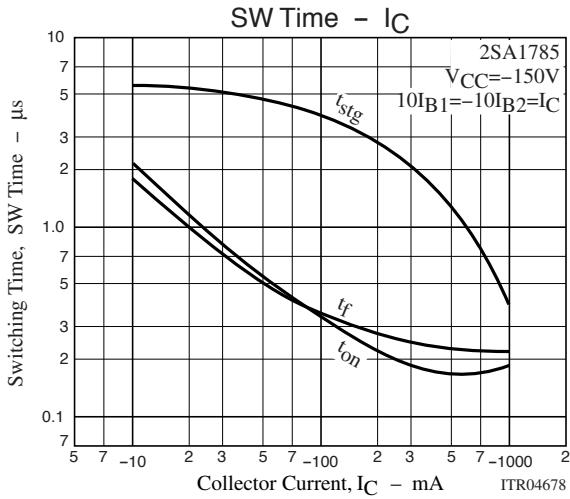
Switching Time Test Circuit



2SA1785/2SC4645



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